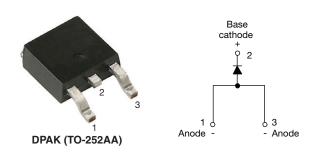
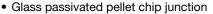


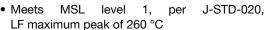
Surface Mount Fast Soft Recovery Rectifier Diode, 8 A



PRIMARY CHARACTERISTICS				
I _{F(AV)} 8 A				
V_{R}	1200 V			
V _F at I _F	1.3 V			
I _{FSM}	150 A			
t _{rr}	80 ns			
T _J max.	150 °C			
Package	DPAK (TO-252AA)			
Circuit configuration	Single			
Snap factor	0.6			

FEATURES







- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Flexible solution for reliable AC power rectification
- High surge, low V_F rugged blocking diode for DC charging stations
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- · On-board and off-board EV / HEV battery chargers
- Renewable energy inverters

DESCRIPTION

The VS-8EWF12SLHM3 fast soft recovery rectifier series has been optimized for combined short reverse recovery time, low forward voltage drop and low leakage current.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Sinusoidal waveform	8	A		
V _{RRM}		1200	V		
I _{FSM}		150	A		
V _F	8 A, T _J = 25 °C	1.3	V		
t _{rr}	1 A, 100 A/µs	80	ns		
TJ	Range	-40 to +150	°C		

VOLTAGE RATINGS			
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA
VS-8EWF12SLHM3	1200	1300	4

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum average forward current	I _{F(AV)}	T _C = 96 °C, 180° conduction half sine wave	8		
Maximum peak one cycle		10 ms sine pulse, rated V _{RRM} applied	125	Α	
non-repetitive surge current	IFSM	10 ms sine pulse, no voltage reapplied	150		
Maximum I ² t for fusing	I ² t	10 ms sine pulse, rated V _{RRM} applied	78	A ² s	
Maximum I-t for fusing		10 ms sine pulse, no voltage reapplied	110	A-5	
Maximum I ² √t for fusing	I²√t	t = 0.1 ms to 10 ms, no voltage reapplied	1100	A²√s	



ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST COI	NDITIONS	VALUES	UNITS
Maximum forward voltage drop	V_{FM}	8 A, T _J = 25 °C		1.3	V
Forward slope resistance	rt	T _J = 150 °C		25.6	mΩ
Threshold voltage	V _{F(TO)}			0.93	V
Maximum reverse leakage current	1	T _J = 25 °C	$V_R = Rated V_{RRM}$	0.1	mA
iviaximum reverse leakage current	IRM	T _J = 150 °C	VR = nateu VRRM	4	IIIA

RECOVERY CHARACTERISTICS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •
Reverse recovery time	t _{rr}	I- at 8 Δ .	270	ns	I _{FM}
Reverse recovery current	I _{rr}	- I _F at 8 A _{pk} 25 Α/μs	4.2	Α	$t_a \mid t_b \mid$
Reverse recovery charge	Q _{rr}	T _J = 25 °C	1	μC	di di Q _{rr}
Snap factor	S		0.6		I I''

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-40 to +150	°C
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2.5	°C/W
Typical thermal resistance, junction to ambient (PCB mount)	R _{thJA} ⁽¹⁾		50	
Approximate weight			1	g
Approximate weight			0.03	oz.
Marking device		Case style DPAK (TO-252AA)	8EWF1	2SH

Note

⁽¹⁾ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 µm) copper 40 °C/W

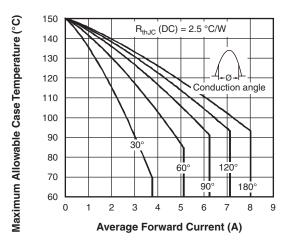


Fig. 1 - Current Rating Characteristics

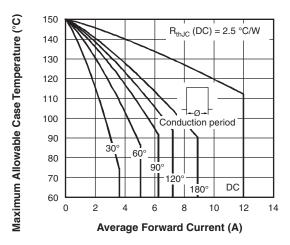


Fig. 2 - Current Rating Characteristics

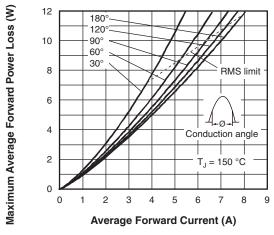


Fig. 3 - Forward Power Loss Characteristics

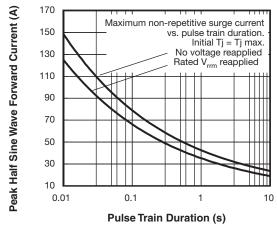


Fig. 6 - Maximum Non-Repetitive Surge Current

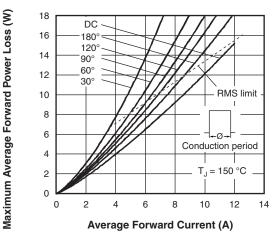


Fig. 4 - Forward Power Loss Characteristics

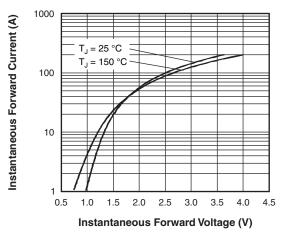


Fig. 7 - Forward Voltage Drop Characteristics

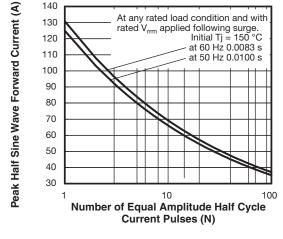
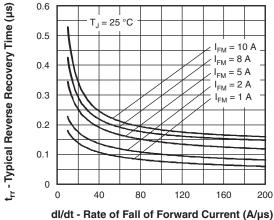


Fig. 5 - Maximum Non-Repetitive Surge Current



ul/ut - mate of rail of rotward current (A/µs)

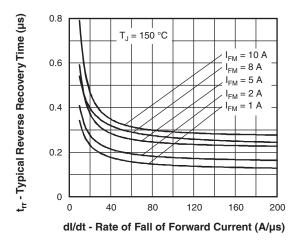


Fig. 9 - Recovery Time Characteristics, T_J = 150 °C

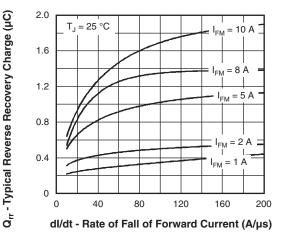


Fig. 10 - Recovery Charge Characteristics, T_J = 25 °C

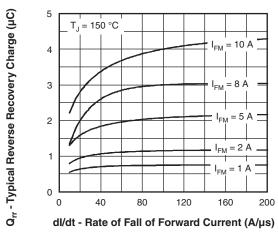


Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C

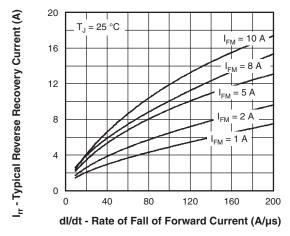


Fig. 12 - Recovery Current Characteristics, T_J = 25 °C

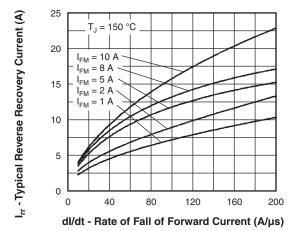


Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

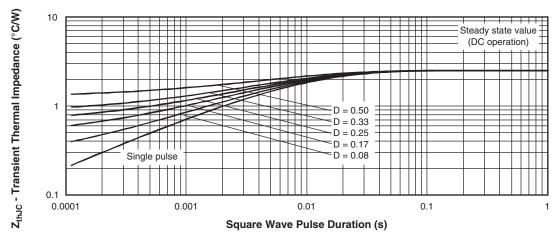


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code VS-8 Ε W 12 S L Н **M3** 8 9 2 (3) [4] 5 (10)6 Vishay Semiconductors product

2 - Current rating (8 = 8 A)

Circuit configuration:

E = single

4 - Package:

W = DPAK (TO-252AA)

5 - Type of silicon:

F = fast soft recovery rectifier

- Voltage code x 100 = V_{RRM} — 12 = 1200 V

7 - S = surface mountable

8 - L = tape and reel (left oriented), for different orientation contact factory

9 - H = AEC-Q101 qualified

10 - Environmental digit:

M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-8EWF12SLHM3	3000	3000	13" diameter reel		

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95519</u>				
Part marking information	www.vishay.com/doc?95518			
Packaging information	www.vishay.com/doc?96495			



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